Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1486	(438/455).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 18:00
S1	2	(("5603779") or ("5882987")).PN.	USPAT	OR	OFF	2005/03/23 19:53
S2	3933	((438/149) or (438/311) or (438/455) or (438/479) or (438/933) or (438/964) or (438/967)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 11:25
S3	3583	S2 and ("GOI" or (germanium adj on adj insulat\$3) naer substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 20:06
S4	8	S2 and ("GOI" or (germanium adj on adj insulat\$3) near substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 20:11
S5	8	S4 and ((dielectric or insulat\$3) near (layer\$1 or film\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 20:11
S6	5	("20020190269" "5603779" "5882987" "6140210" "6150239"). PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/23 20:09
S7	0	("6833195").URPN.	USPAT	OR	OFF	2005/03/23 20:10
S8	6967	("GOI" or (germanium adj on adj insulat\$3) near substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:47
S9	51	("GOI" or (germanium adj on adj insulat\$3) near substrate\$1) same ((dielectric or insulat\$3) near (film\$1 or layer\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 20:13

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S10	50	S9 not S5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 20:13
S11	4	S10 and ((wafer\$1 or substrate\$1) near2 bond\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 20:19
S12	46	S10 not S11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 20:19
S13	19	((epitaxial\$2 near ("Ge" or germanium)) near (layer\$1 or film\$1)) same ((dielectric or insulat\$3) near (layer\$1 or film\$1)) same (substrate\$1 or wafer\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:28
S14	0	("2004/0150006").URPN.	USPAT	OR	OFF	2005/03/23 20:46
S15	560	((epitaxial\$2 near ("Ge" or germanium)) near (layer\$1 or film\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 17:52
S16	348	S15 and bond\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/23 21:09
S17	23	S16 and S2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2005/03/23 21:09
S18	561	((epitaxial\$2 near ("Ge" or germanium)) near (layer\$1 or film\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/24 17:52

S19	99	((epitaxial\$2 adj ("Ge" or germanium)) adj (layer\$1 or film\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2005/03/24 17:52
S20	0	(((germanium adj on adj insulat\$3) near substrate\$1) same bond\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:48
S21	0	(((germanium adj on adj insulat\$3) near substrate\$1) and bond\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:48
S22	0	((germanium adj on adj insulat\$3) near substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:49
S23	0.	((germanium adj on adj insulat\$3) near3 substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:49
S24	. 0	((germanium adj on adj insulat\$3) same substrate\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:49
S25	0	(germanium adj on adj insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:50
S26	6974	(germanium adj on adj insulat\$3) or "GOI"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:51

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S27	0	(germanium adj on adj insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:51
S28	0	(germanium adj on adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:52
S29		germanium adj on adj insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:52
S30	744	germanium near2 insulat\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:30
S31	569	S30 same (substrate\$1 or wafer\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:53
S32	337	S31 and bond\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/03/28 15:54
S33	. 10	("5315143" "5461250" "5583059" "5679970" "5917210" "6387739" "6396108" "6548870" "6580129" "6617636").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/28 16:28
S34	4	("5313075" "5627084" "5726459" "5869359").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/03/28 16:31
S35	0	("6501135").URPN.	USPAT	OR	OFF	2005/03/28 16:32
S36	1	2004-814137.NRAN.	DERWENT	OR	OFF	2005/03/28 16:38
S37	1	2004-814137.NRAN.	DERWENT	OR	OFF	2005/03/28 16:38

S38	4231	((438/149) or (438/311) or (438/455) or (438/479) or (438/933) or (438/964) or (438/967)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/22 16:29
S39	4231	((438/149) or (438/311) or (438/455) or (438/479) or (438/933) or (438/964) or (438/967)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/27 16:08
S40	58	S39 and ((("Ge" or germanium) near2 (layer\$1 or film\$1)) near5 insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:43
S41	7949	((("Ge" or germanium) near2 (layer\$1 or film\$1)) near5 insulat\$3) or ("GOI" or germanium adj on adj insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/22 16:45
S42	7219	(germanium or Ge) same SOI	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON .	2005/08/23 18:41
S43	112	S42 and goi	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/23 18:43
S44	1	("6933566").PN.	USPAT -	OR	OFF	2005/08/23 18:43
S45	5	("20020190269" "5603779" "5882987" "6140210" "6150239"). PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/12/27 15:49
S46	0	("6833195").URPN.	USPAT	OR	OFF	2005/12/27 15:49
S47	4481	((438/149) or (438/311) or (438/455) or (438/479) or (438/933) or (438/964) or (438/967)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/12/27 16:12

S48	101	S47 and ("GOI" or "GeSOI" or (germanium near2 insulat\$3) or (germanium near2 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT;	OR	ON	2005/12/27 16:27
S49	14057	("GOI" or "GeSOI" or (germanium near2 insulat\$3) or (germanium near2 oxide))	IBM_TDB US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:33
S50	1239	S49 and (("Ge" or germanium) near5 (insulat\$3 or dielectric))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
S51	429	S50 and (epitaxial\$2 near5 ("Ge" or germanium))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
S52	305	S51 and bond\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
S53	15229	("GOI" or "GeOI" or (germanium near2 insulat\$3) or (germanium near2 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 15:32
S54	104	S47 and S53	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:33
S55	3	S54 not S48	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:33

S56	1243	S53 and (("Ge" or germanium) near5 (insulat\$3 or dielectric))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 15:31
S57	429	S56 and (epitaxial\$2 near5 ("Ge" or germanium))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 15:36
S58	305	S57 and bond\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/27 16:34
S59	0	("2005/0067377").URPN.	USPAT	OR	OFF	2005/12/27 16:36
S60	1	("3997381").PN.	USPAT	OR	OFF	2006/11/20 19:44
S61	1	("4601779").PN.	USPAT	OR	OFF	2006/11/20 19:44
S62	13807	(("Ge" or germanium) with (insulat\$3 or dielectric))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 15:32
S63	13807	(("Ge" or germanium) with (insulat\$3 or dielectric))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 15:32
S64	8437	"GOI" or "GeOI" or ge\$1on\$1insulat\$3 germanium\$1on\$1insulat\$3 or (germanium adj on adj insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO;	OR	OFF	2007/05/26 15:35
			DERWENT; IBM_TDB			
S65	21779	S63 or S64	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 15:36

S66	5645	epitax\$3 with ("Ge" or germanium)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 16:27
S67	1906	S65 and S66	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 15:37
S68	96842	thick\$3 with (insulat\$3 or dielectric)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 15:38
S69	386	S67 and S68	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 15:38
S70	460566	"438"/\$.ccls. or "257"/\$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 15:39
S71	374	S69 and S70	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 15:51
S72	1277	(438/479).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 15:52

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S73	2223	(438/149).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 16:32
S74	85	(257/E21.092).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 16:23
S75	517	(257/E21.102).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 16:24
S76	720	(257/E21.122).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 16:26
S77	669	(257/E21.127).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 16:26
S78	306	S77 and ("Ge" or germanium)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/05/26 16:27
S79	310	(438/933).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/05/26 18:00

S80	1	germanium and (first adj substrate) and (second adj substrate) and	US-PGPUB	OR	OFF	2007/05/26 16:35
		bond\$3 and (GOI adj substrate).clm.				